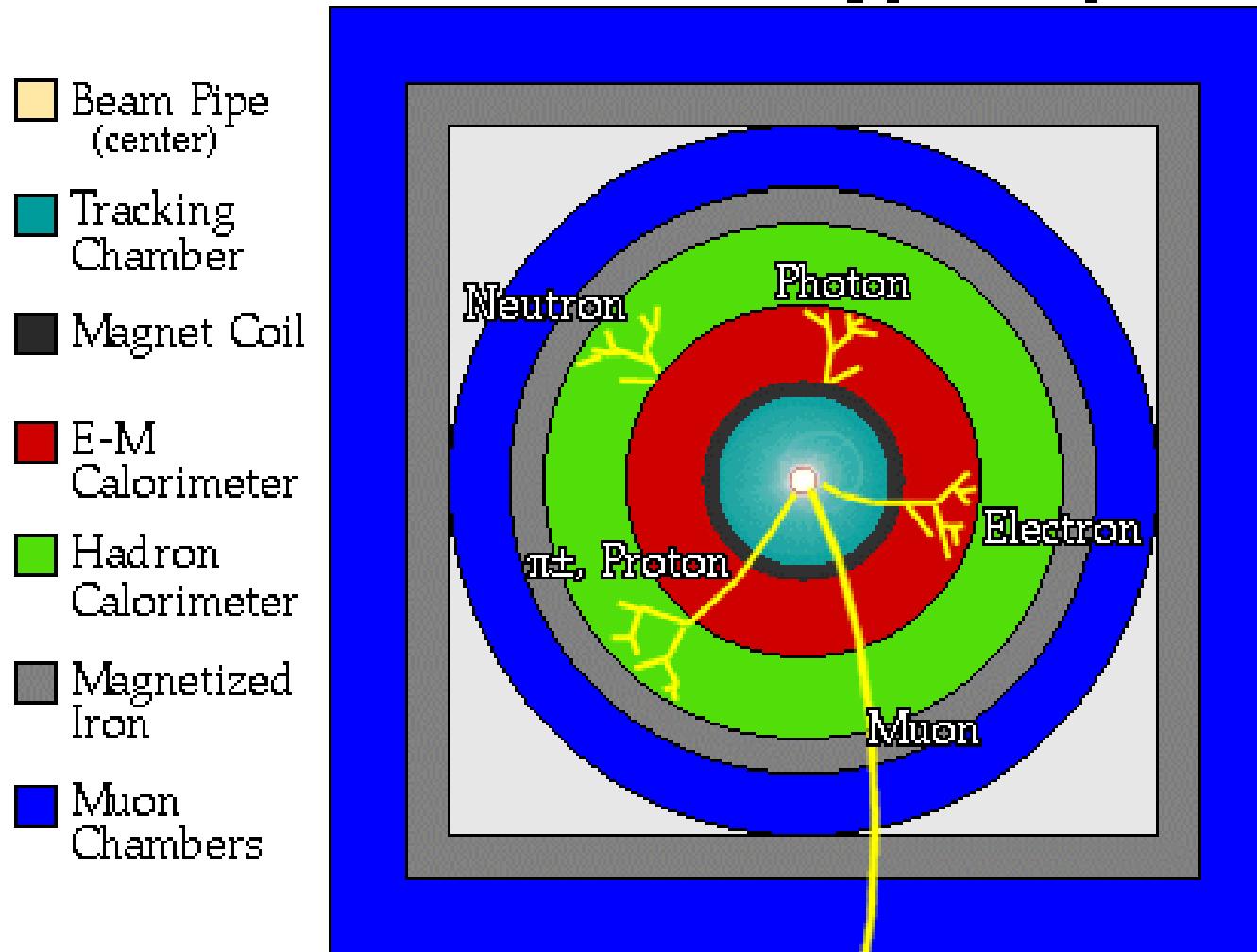


Generic Detector

A detector cross-section, showing particle paths



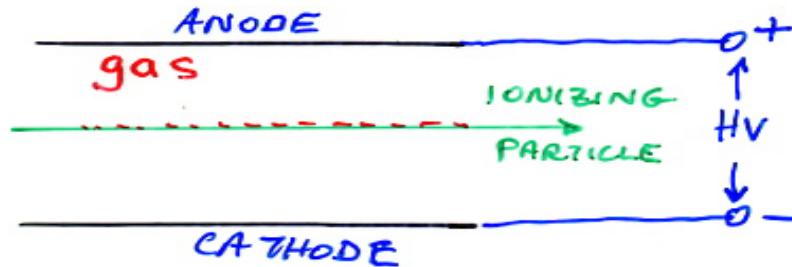
- ▶ Layers of Detector Systems around Collision Point

Tracking Detectors

- Observe particle trajectories in space with as little disturbance as possible
 - use a thin ($gm.cm^{-2}$) detector
 - Scintillators $(\sigma \sim cm)$
 - Scintillating fibres $(\sigma \sim 150\mu)$
 - Gas trackers $(\sigma \sim 150\mu)$
 - Solid state trackers $(\sigma \sim 10\mu)$
 - Gas Based Detectors
 - Multiwire proportional chamber
 - Drift Chamber
 - Time projection chamber
 - Gas microstrip
 - GEM (gas electron multiplier)

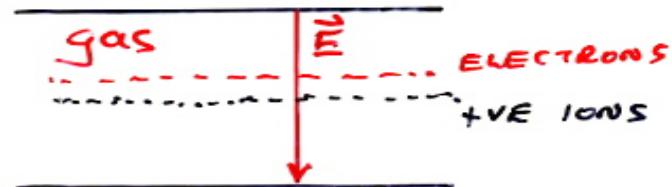
IONIZATION DETECTORS

20



$$\sim \frac{1 \text{ ION}}{30 \text{ eV} \frac{dE}{dx}}$$

Time

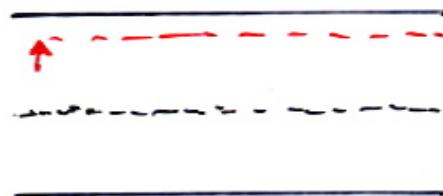


$$\sim \frac{10^2 \text{ IONS}}{\text{cm} \frac{dE}{dx}}$$

DRIFT VELOCITY

$$\bar{u} = \mu(E) \cdot E$$

MOBILITY



$$\frac{10^2 \text{ e m/s}}{10 \text{ ms}} \approx 50 \Omega$$

$1 \mu\text{V}$

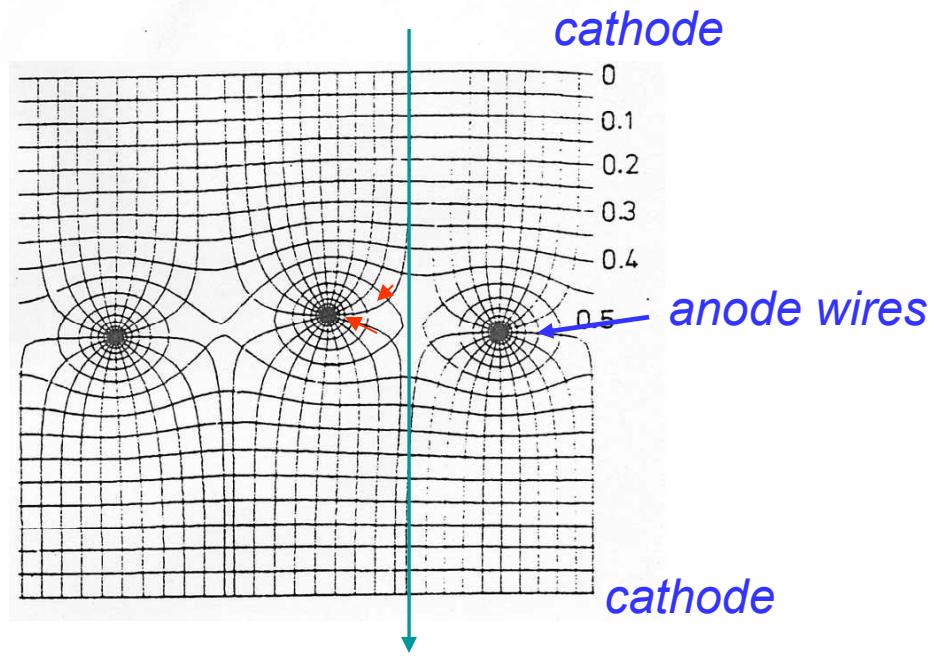
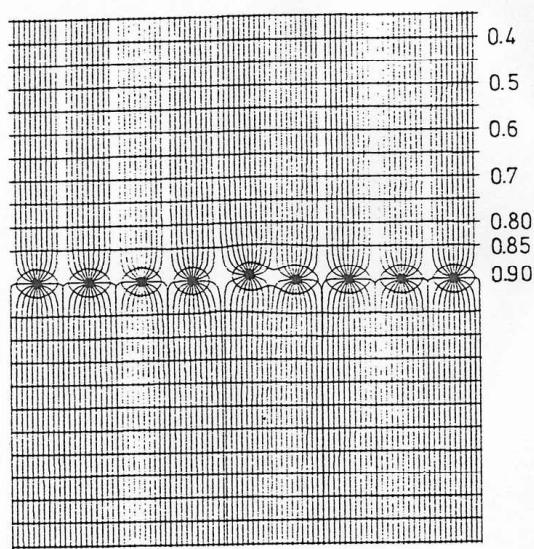
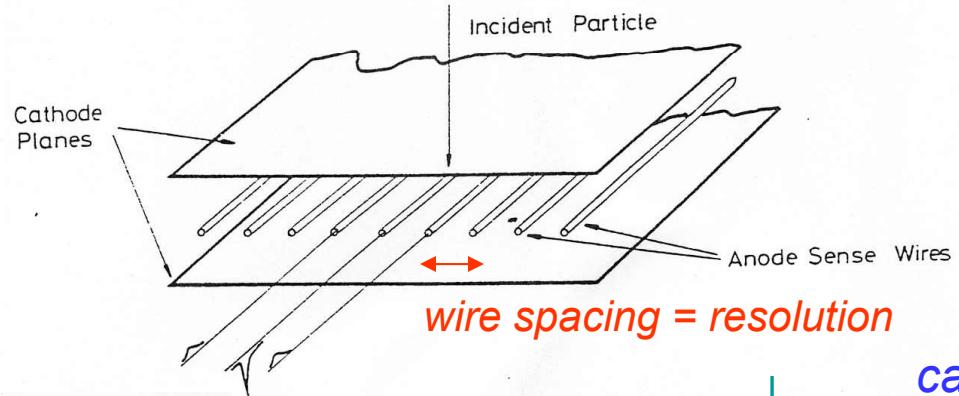
SIGNAL

small - amplification?

SIGNAL

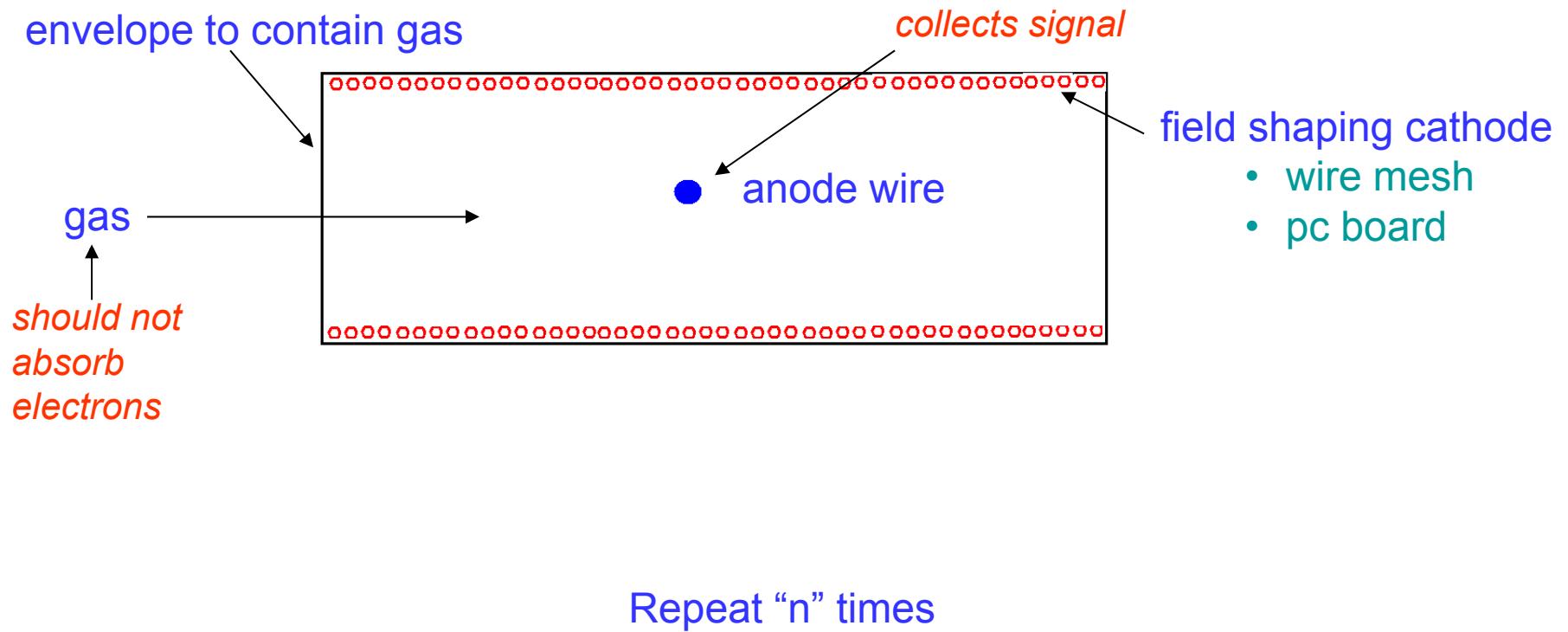


Multiwire Proportional Chamber

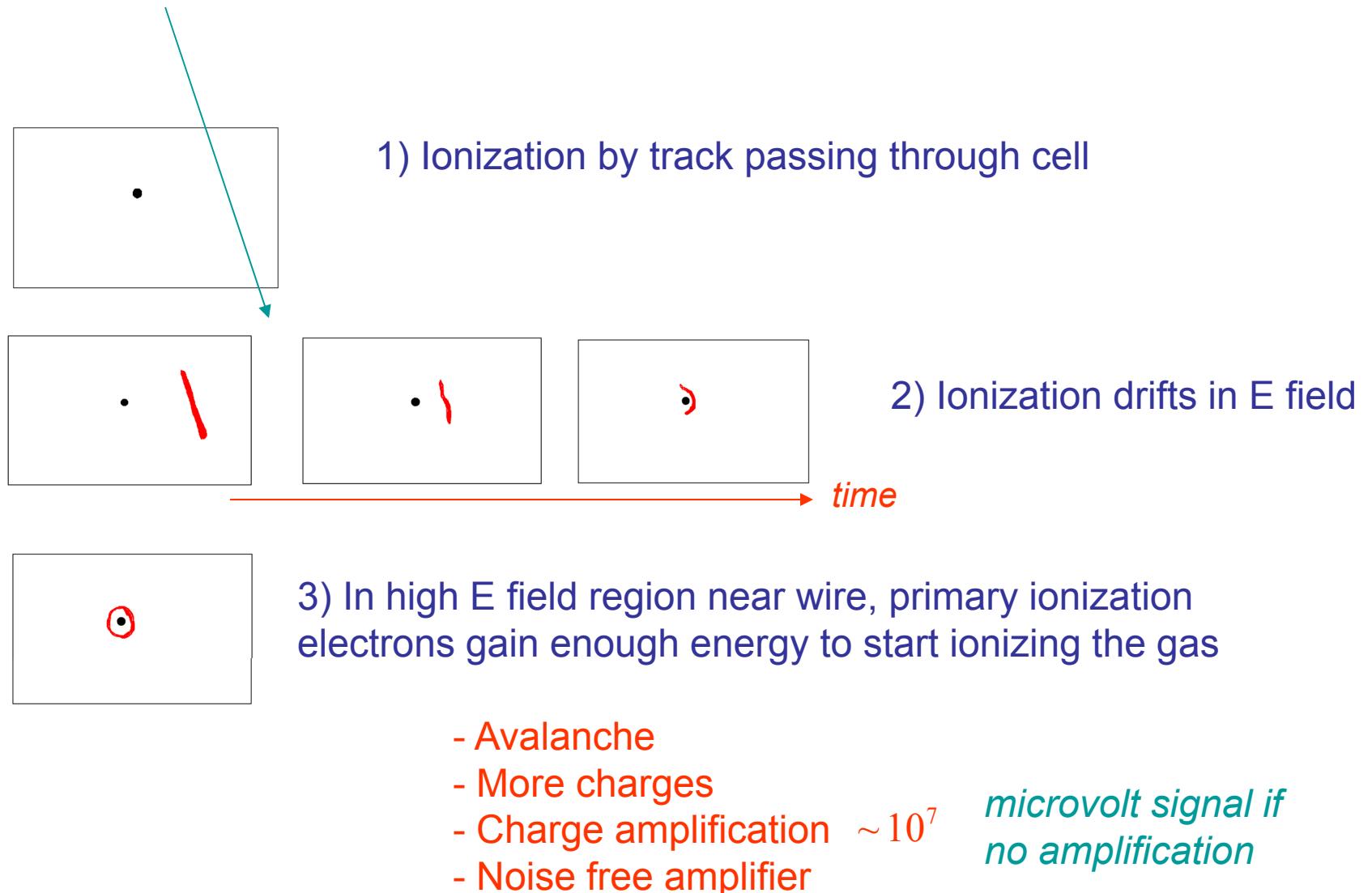


Drift Chamber – measure arrival time of charge = spatial resolution

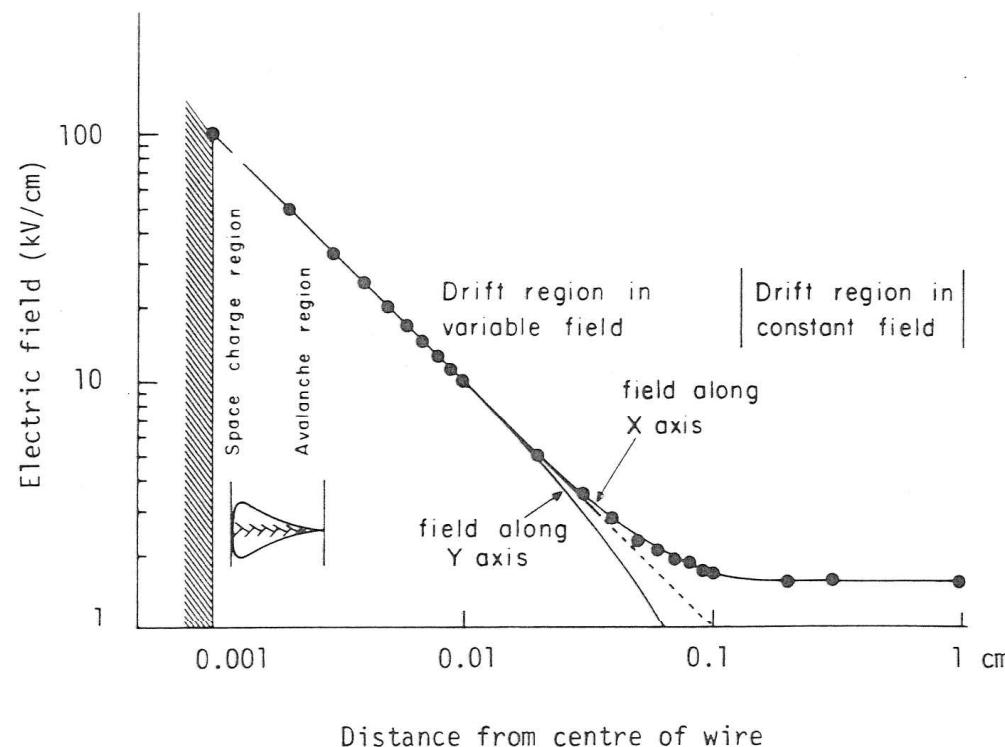
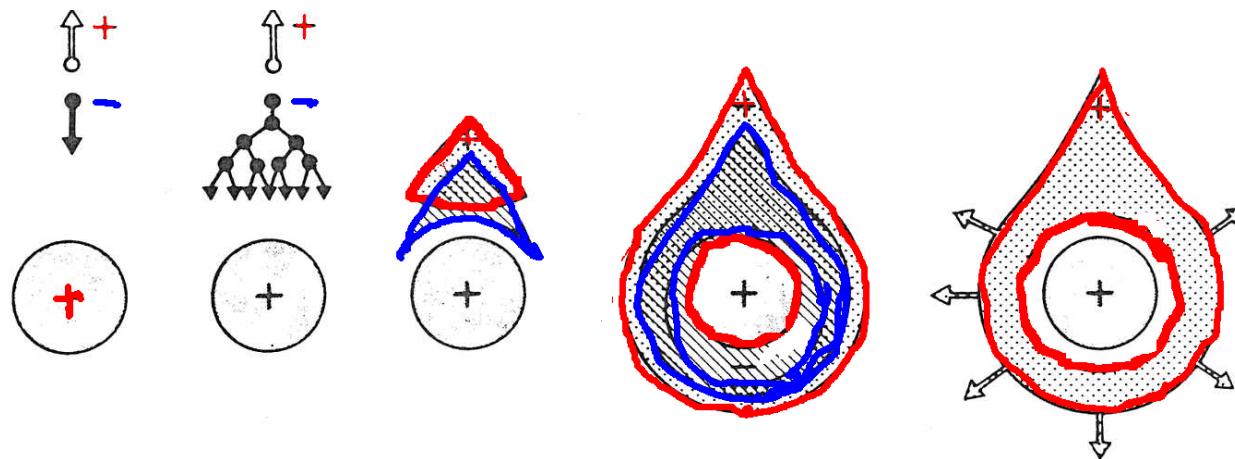
Schematic of Wire Chamber Cell



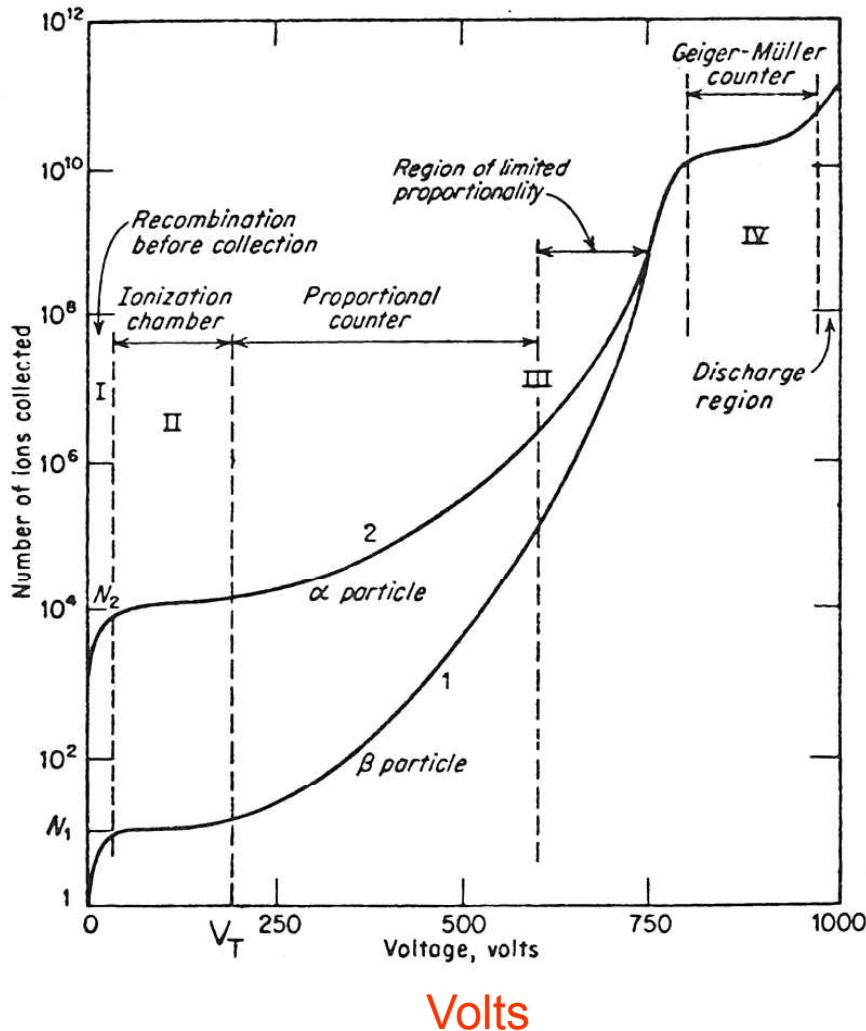
3 stages in signal generation



Gas Amplification



Behaviour as Voltage Increased



- Collection – Recombination dominated
- All charge collected
- Amplification by gas multiplication
 - Still proportional – particle ident
- Saturation
- Breakdown – Geiger/Mueller

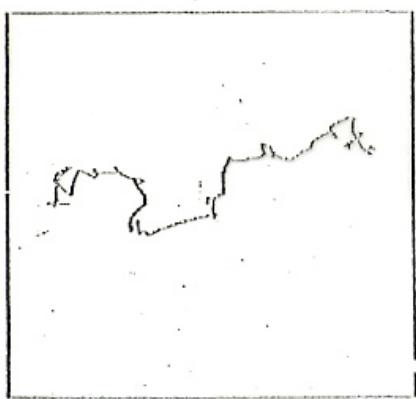
Diffusion



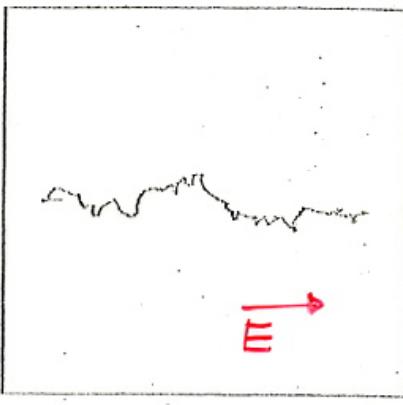
$E/P = 10$



$E/P = 100$



$E/P = 500$



$E/P = 1500$

$$\frac{E}{P} = \frac{v/\text{cm}}{\text{mm Hg}}$$

- Ions & electrons diffuse in space
 - E field determines average direction
-
- Collisions limit velocity
 - Maximum average velocity
=Drift velocity

Diffusion

- Ions and electrons diffuse under influence of electric field
 - Maxwell velocity distribution

$$\langle v \rangle = v = \sqrt{\frac{8kT}{\pi m}}$$

$$v_e \sim 10^6 \text{ cm.s}^{-1} \quad v_{I^+} \sim 10^4 \text{ cm.s}^{-1}$$

- From Kinetic theory , after t , linear distribution due to diffusion

$$\frac{dN}{dx} = \frac{N_0}{\sqrt{4\pi Dt}} \exp\left\{-\frac{x^2}{4Dt}\right\}$$

number of particles *Diffusion coefficient*

RMS Spread

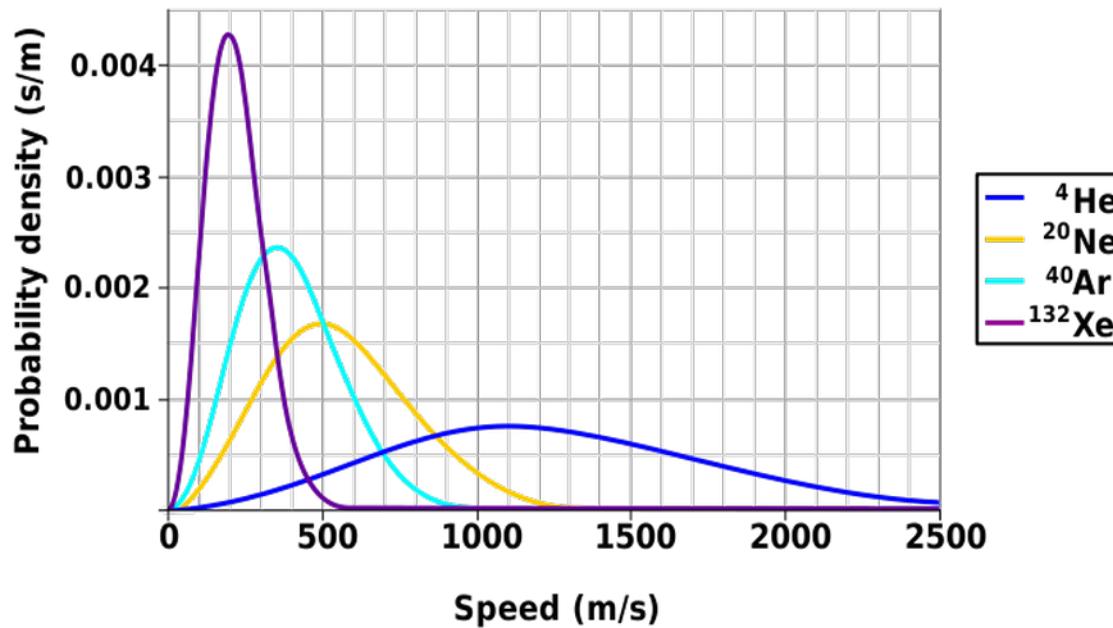
$$\sigma(x) = \sqrt{2Dt} \quad \text{2-d}$$

$$\sigma(r) = \sqrt{6Dt} \quad \text{3-d}$$

about 1mm after 1 sec in air

MAXWELL DISTRIBUTION

Maxwell-Boltzmann Molecular Speed Distribution for Noble Gases



$$\langle v \rangle = \int_0^\infty v f(v) dv = \sqrt{\frac{8kT}{m\pi}}$$

$$\sqrt{\langle v^2 \rangle} = \sqrt{\int_0^\infty (v^2 f(v) dv)^{1/2}} = \sqrt{\frac{3kT}{m}}$$

Mobility

- For a classical gas

$$\mu = \frac{2}{3\sqrt{\pi}} \frac{q}{p\sigma_0} \sqrt{\frac{kT}{m}} = \frac{u}{E}$$

drift velocity
electric field

q, m ion charge and mass

p gas pressure

σ_0 ion scattering cross section

$\sigma_o \equiv \sigma_o (E)$

ELECTRIC
FIELD

- In argon

$$\mu_e = 40 \frac{\mu\text{m}/\text{ns}}{\text{kV}/\text{cm}}$$

$$\mu_{I^+} = 0.1 \frac{\mu\text{m}/\text{ns}}{\text{kV}/\text{cm}}$$

- Electrons collected quickly compared to +ve ions

Diffusion and Drift Chamber Accuracy

$$D = \frac{1}{3} v \lambda \quad \text{Diffusion coefficient from kinetic theory}$$

$$\lambda = \frac{1}{\sqrt{2}} \frac{kT}{\sigma_0 p} \quad \text{Mean free path}$$

$$D = \frac{2}{3\sqrt{\pi}} \frac{1}{\sigma_0 p} \sqrt{\frac{(kT)^3}{m}}$$

$$\text{In argon} \quad D_e \sim 10 \mu^2 / ns$$

Diffusion gives limit on spatial accuracy drift chamber

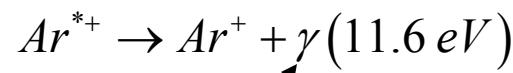
- To reduce D
 - Lower temperature
 - Raise pressure (reduce mobility)

Working Gas

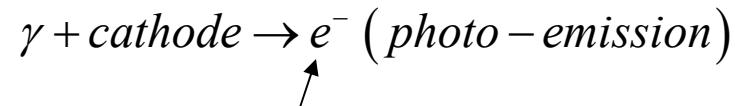
- Noble gases give multiplication at lowest electric field
 - Polyatomic gases have non-ionization energy loss mechanisms
- Choose cheap noble gas with low ionization potential
 - Krypton X *rare, expensive*
 - Xenon X
 - Argon OK *cheap – welding etc*

Argon

- Cheap, safe, non-reactive
 - remove electro-negative contaminants O_2, CO_2, H_2O
- Pure argon limited to gain $\leq 10^3$
- Many excited ions produced during avalanche



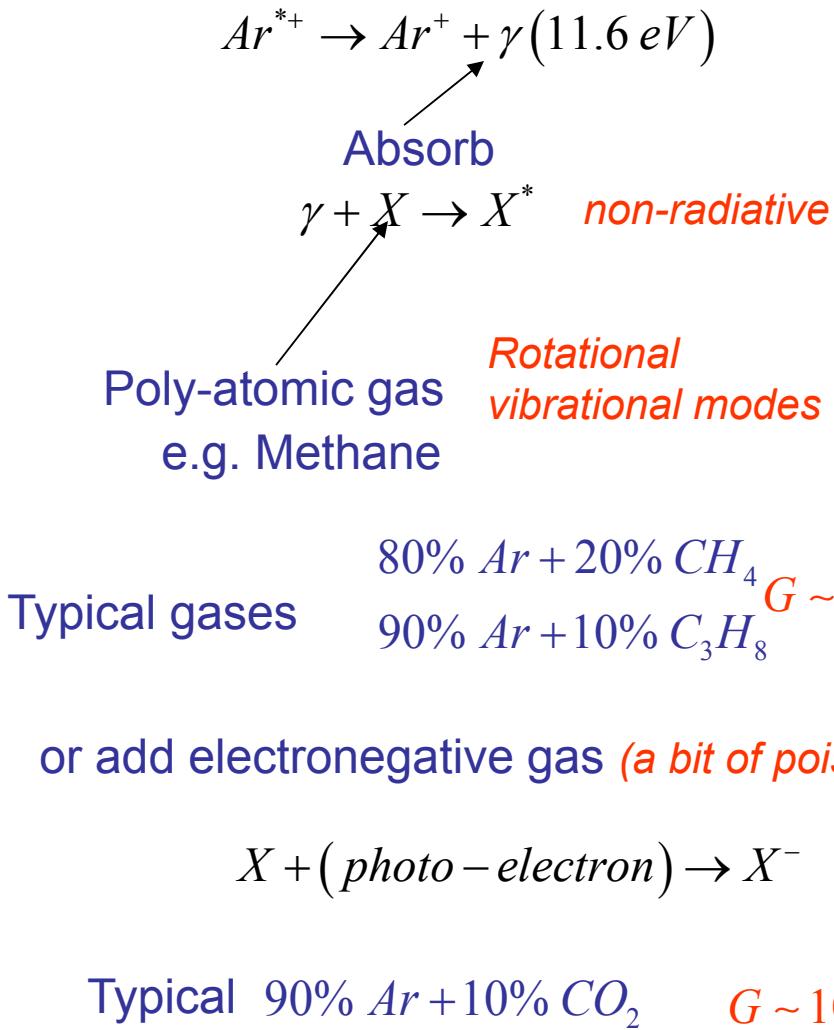
absorbed on cathode



returns to anode - breakdown

- Absorb γ - quenchers

Quenchers

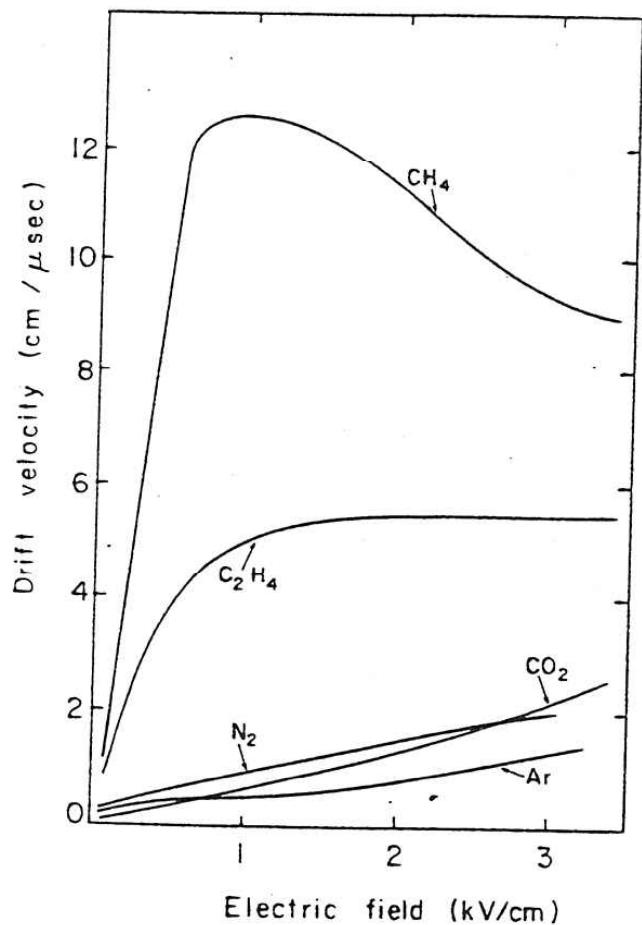


Polymerization

- Organic quenchers polymerize
 - Deposits on cathodes
 - high resistance
 - ion buildup – discharge
 - sparks, broken wires
 - Add non-polymerizing agent – water methylal
- Magic Gas $75\% Ar$
 $24.5\% (CH_3)_2CHCH_3$
 0.5% Freon
 trace methylal
 $1\% H_2O$

SMALL ADMIXTURES CAN
MAKE A LARGE DIFFERENCE
IN DRIFT VELOCITY →

DIFFERENT GASES ↓



ELECTRON
SCATTERING
CROSS
SECTION →

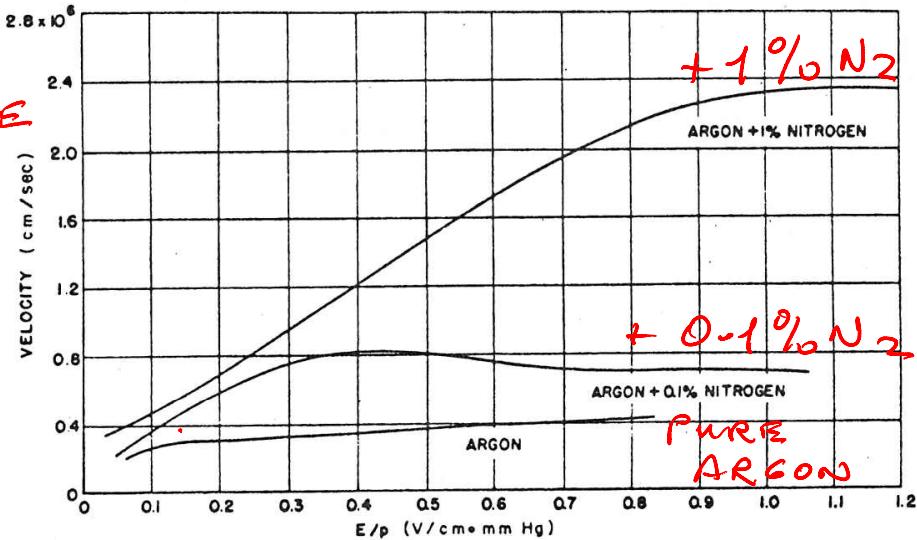
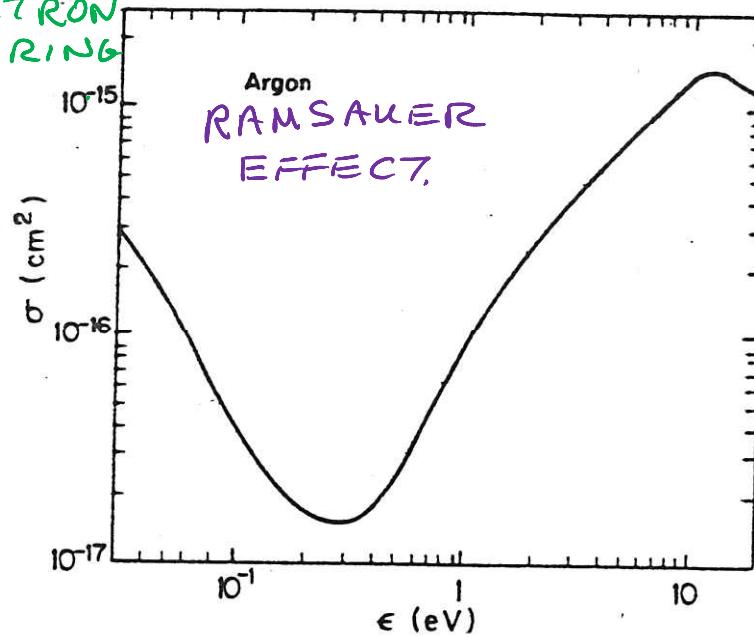
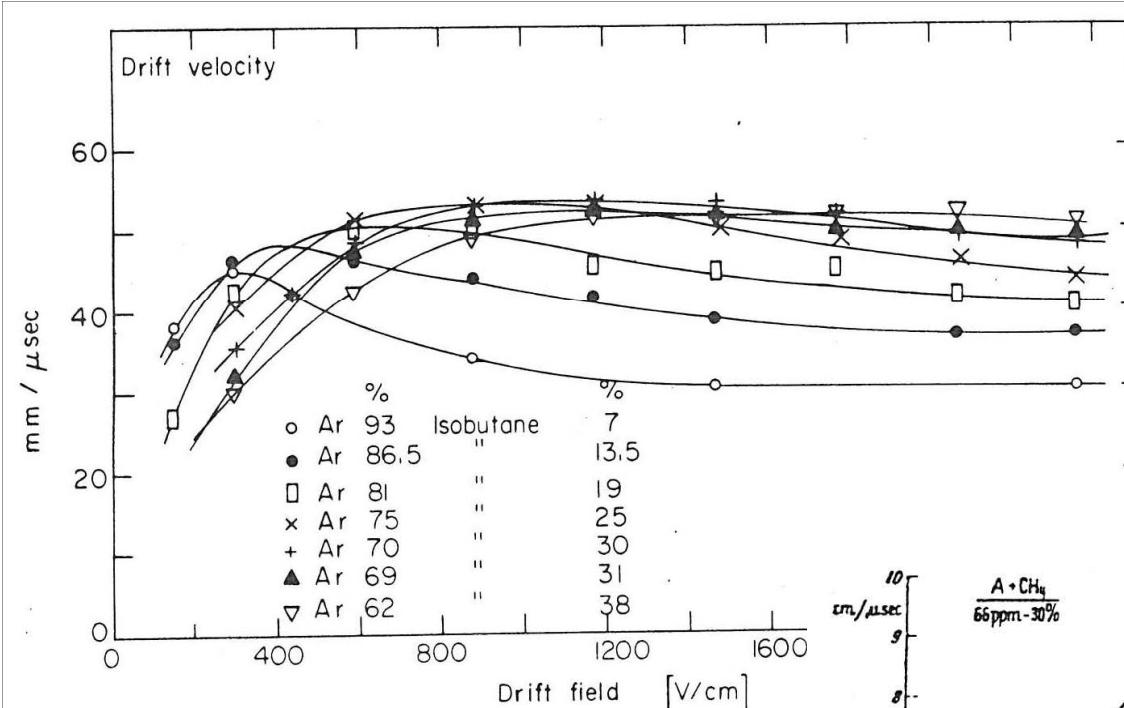


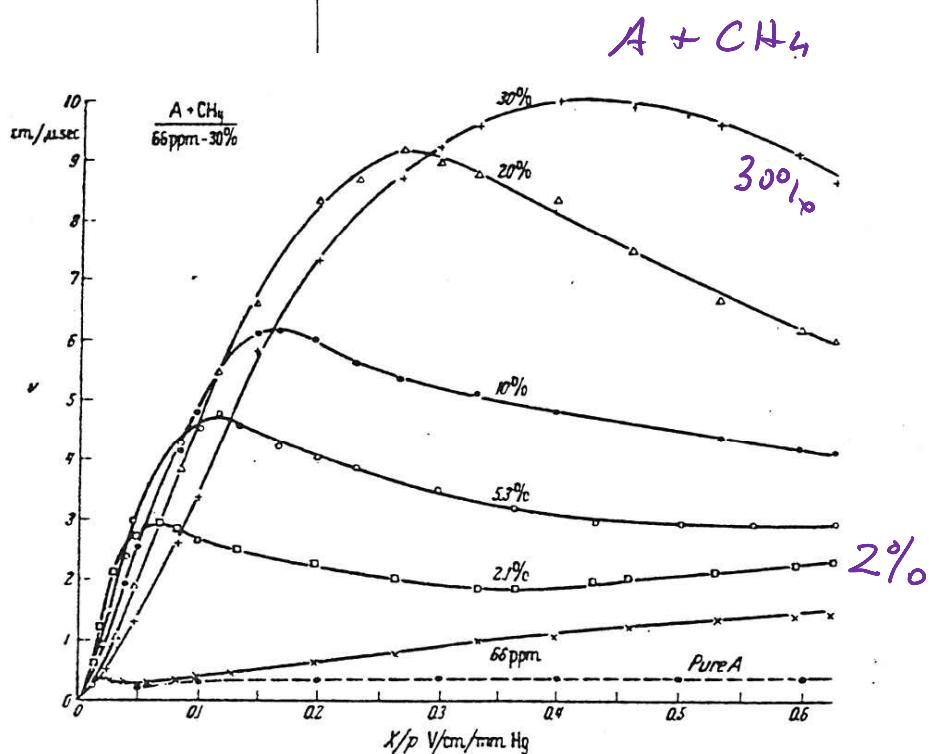
Fig. 25 Drift velocity of electrons in pure argon, and in argon with small added quantities of nitrogen. The very large effect on the velocity for small additions is apparent²².

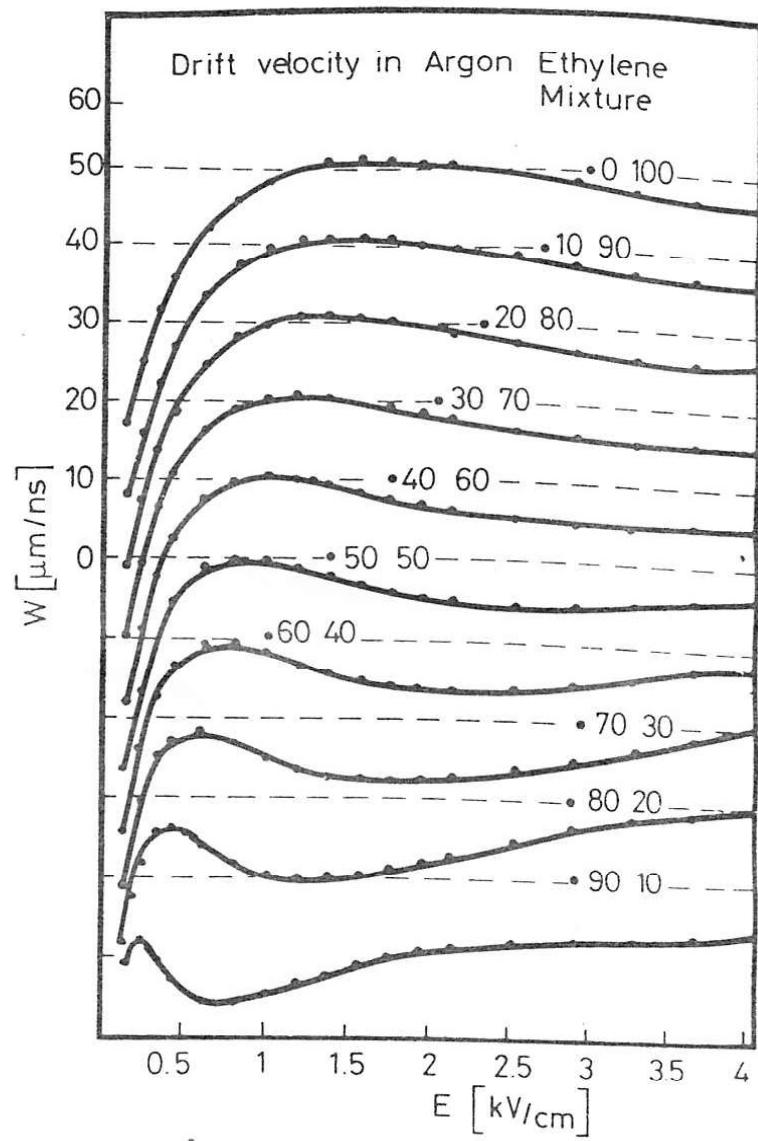
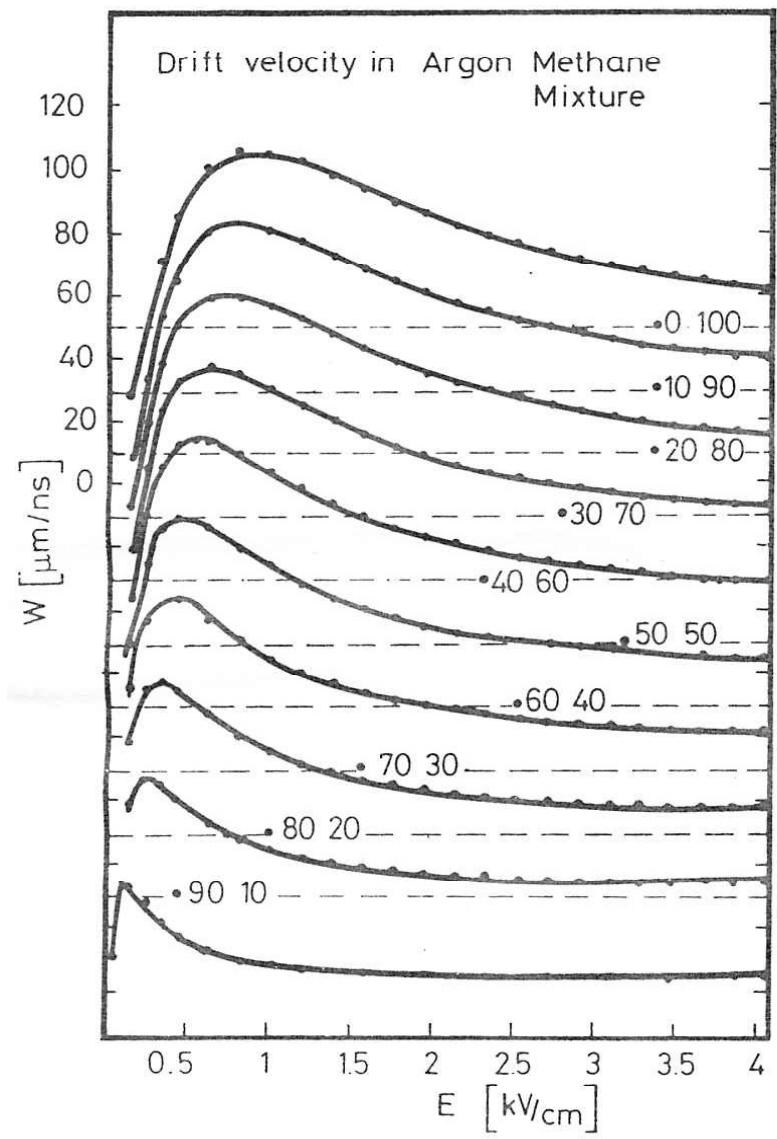


Gas Admixtures

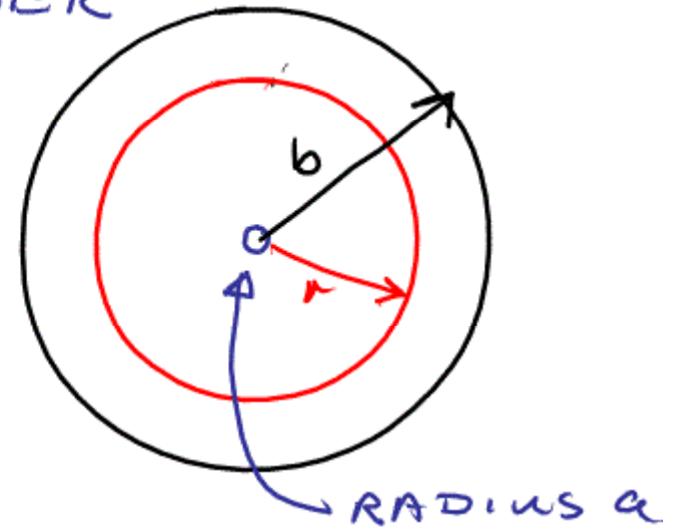
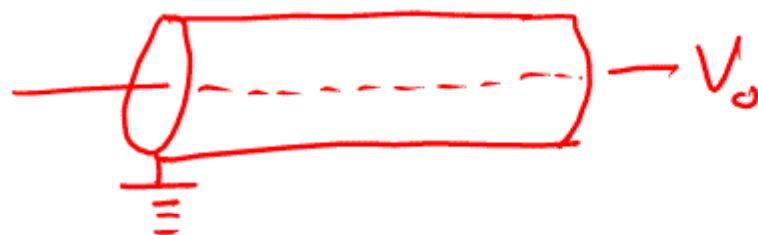


WANT DRIFT VELOCITY TO
BE INDEPENDENT OF THE
ELECTRIC FIELD





WIRE IN COAXIAL CYLINDER



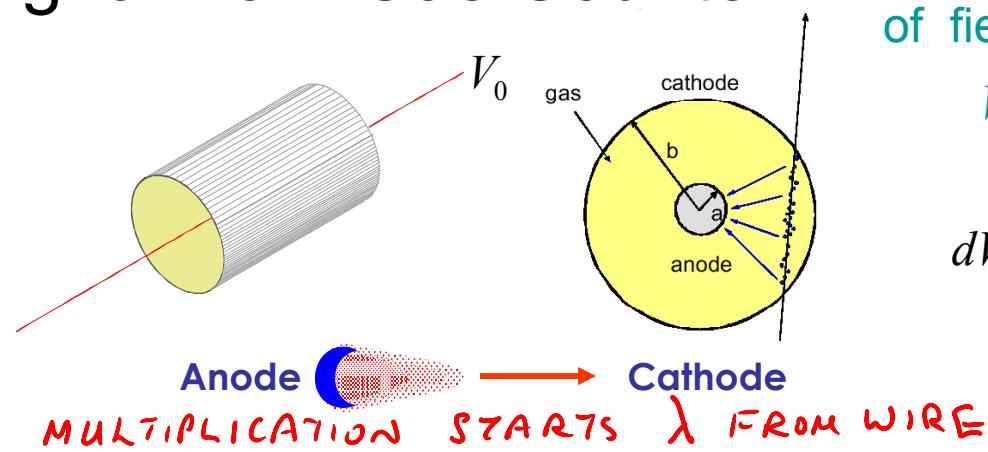
$$E(r) = \frac{CV_0}{2\pi\epsilon_r} \frac{1}{r}$$

POTENTIAL $\phi(r) = -\frac{CV_0}{2\pi\epsilon_r} \ln\left(\frac{r}{a}\right)$

WIRE
RADIUS

$$C = \frac{2\pi\epsilon_r}{\ln(b/a)} \quad \text{PER UNIT LENGTH}$$

Signal from Gas Counter



charge q moved by dr

$$dV = \frac{Q}{lCV_0} \frac{d\phi(r)}{dr} dr$$

length of counter \xrightarrow{l} capacitance/unit length

- Electrons produced in avalanche close to anode wire
- Small dr – small signal
- +ve ions drift across whole radius
- Large dr – large signal

CHARGE
electrostatic energy potential energy of q

$$W = \frac{1}{2} lCV_0^2$$

$$W = Q\phi(r)$$

$$dW = lCV_0 dV \quad \underline{=} \quad dW = Q \frac{d\phi(r)}{dr} dr$$

$$lCV_0 dV = Q \frac{d\phi(r)}{dr} dr$$

$$dV = \frac{Q}{lCV_0} \frac{d\phi(r)}{dr} dr \quad \phi(r) = -\frac{CV_0}{2\pi\epsilon_0} \ln \frac{r}{a}$$

$$V_{electron} = -\frac{Q}{lCV_0} \int_{a+\lambda}^a \frac{d\phi(r)}{dr} dr = -\frac{Q}{2\pi\epsilon_0 l} \ln \frac{a+\lambda}{a}$$

$$V_{ion} = +\frac{Q}{lCV_0} \int_{a+\lambda}^b \frac{d\phi(r)}{dr} dr = -\frac{Q}{2\pi\epsilon_0 l} \ln \frac{b}{a+\lambda}$$

$$\frac{V_{electron}}{V_{ion}} = \ln \frac{a+\lambda}{a} / \ln \frac{b}{a+\lambda}$$

Typically 1%

Time Development of Signal

- Assume

- All signal comes from ions
- Start from a

$$V(t) = -\frac{Q}{4\pi\epsilon_0 l} \ln \left(1 + \frac{\mu^+ C V_0}{\pi\epsilon_0 a^2} t \right) = -\frac{Q}{4\pi\epsilon_0 l} \ln \left(1 + \frac{t}{t_0} \right)$$

$$t_0 = \frac{a^2 \pi \epsilon_0}{\mu^+ C V_0}$$

$$V(t) = \int_0^t dV = \int_a^{r(t)} \frac{dV}{dr} dr = \frac{Q}{l C V_0} \int_a^{r(t)} \frac{d\phi(r)}{dr} dr$$

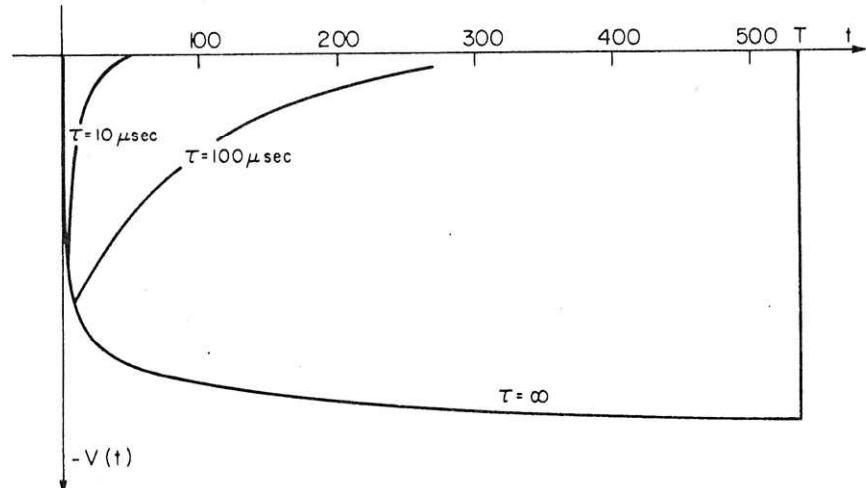
$$= \frac{Q}{l C V_0} \left[-\frac{C V_0}{2\pi\epsilon_0} \ln \frac{r}{a} \right]_a^{r(t)} = -\frac{Q}{2\pi\epsilon_0 l} \ln \frac{r(t)}{a}$$

$$\frac{dr}{dt} = \mu^+ E = \frac{\mu^+ C V_0}{2\pi\epsilon_0} \frac{1}{r}$$

$$\int_a^r r dr = \frac{\mu^+ C V_0}{2\pi\epsilon_0} \int_0^t dt$$

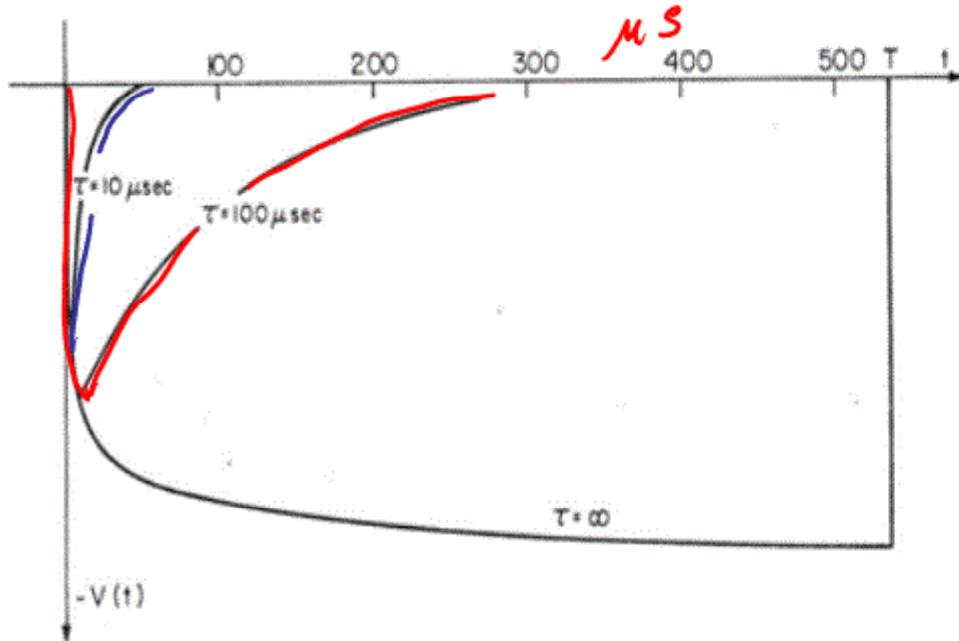
$$r(t) = \sqrt{a^2 + \frac{\mu^+ C V_0}{\pi\epsilon_0} t}$$

$$r(0) = a$$



Typically get 50% of signal in $10^{-3} \text{ T} \sim 700 \text{ ns}$

RC differentiation for fast signal



TYPICAL

$$a = 10\mu\text{m}, b = 8\text{mm}$$

$$C = 8\text{pF/m}$$

$$\mu^+ = 1.7 \text{ cm}^2 \text{s}^{-1} \text{V}^{-1} \text{atm}^{-1}$$

$$V_0 = 3\text{kV}$$

SIGNAL GROWS QUICKLY 50% IN $10^{-3}T \sim 700\text{ns}$

TERMINATE COUNTER WITH R

$$\tau = RC$$

TOTAL DRIFT TIME $T = \frac{t_0}{a^2} (b^2 - a^2)$